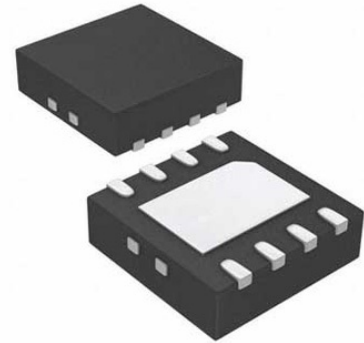


PowerTrench Power Stage 30 V Asymmetric Dual N-Channel MOSFET

Manufacturers	ON Semiconductor, LLC
Package/Case	QFN-8
Product Type	Transistors
RoHS	Green
Lifecycle	



Images are for reference only

Please submit RFQ for FDMS3606S or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

This device includes two specialized N-Channel MOSFETs in a dual PQFN package. The switch node has been internally connected to enable easy placement and routing of synchronous buck converters. The control MOSFET (Q1) and synchronous SyncFET (Q2) have been designed to provide optimal power efficiency.

Features

Q1: N-ChannelMax = 10 V, = 11 mΩ at = 11 A

Q2: N-ChannelMax = 10 V, = 2.8 mΩ at = 23 A

Application

ONSEMI

Related Products



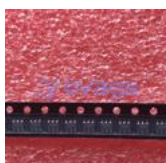
[FDC645N](#)

ON Semiconductor, LLC
SSOT-6



[FDC637BNZ](#)

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SSOT-6



[FDC6305N](#)

ON Semiconductor, LLC
SSOT-6



[FDC602P](#)

ON Semiconductor, LLC
SOT163



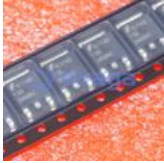
[FDD8647L](#)

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